TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC74HC573AP, TC74HC573AF**

#### Octal D-Type Latch with 3-State Output

The TC74HC573A is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate  $\rm C^2MOS$  technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

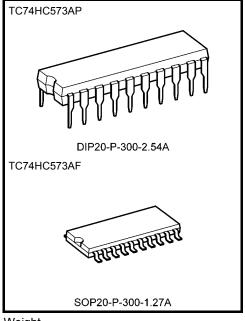
Its 8-bit D-type latche is controlled by a latch enable input (LE) and an output enable input ( $\overline{OE}$ ).

When the  $\overline{\rm OE}$  input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

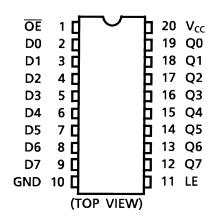
- High speed:  $t_{pd} = 13 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_a = 25 \text{°C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: | I<sub>OH</sub> | = I<sub>OL</sub> = 6 mA (min)
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V<sub>CC</sub> (opr) = 2 to 6 V
- Pin and function compatible with 74LS573



Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

#### **Pin Assignment**



## **IEC Logic Symbol**

OE (1) EN C 1	
D4 (6) (15) (7) (14) (8) (13)	Q0 Q1 Q2 Q3 Q4 Q5 Q6 Q7

## **Truth Table**

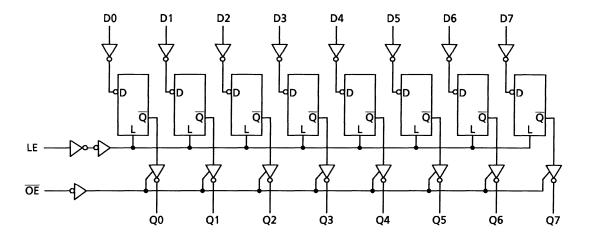
	Output		
ŌĒ	LE	D	Q
Н	Х	Х	HZ
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

HZ: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

## **System Diagram**



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#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	–0.5 to 7	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±35	mA
DC V <sub>CC</sub> /ground current	Icc	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to  $65^{\circ}C$ . From Ta = 65 to  $85^{\circ}C$  a derating factor of -10 mW/°C shall be applied until 300 mW.

## **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2 to 6	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	٧
Operating temperature	T <sub>opr</sub>	−40 to 85	°C
		0 to 1000 (V <sub>CC</sub> = 2.0 V)	
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500 (V <sub>CC</sub> = 4.5 V)	ns
		0 to 400 (V <sub>CC</sub> = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

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## **Electrical Characteristics**

### **DC Characteristics**

Characteristics	Symbol	Test Condition			-	Га = 25°(			a = o 85°C	Unit
	- <b>,</b>			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
				2.0	1.50	_	_	1.50	_	
High-level input voltage	$V_{IH}$		_	4.5	3.15			3.15	_	V
ŭ				6.0	4.20	—	_	4.20	_	
				2.0	_		0.50	_	0.50	
Low-level input voltage	$V_{IL}$		_	4.5	_	_	1.35	_	1.35	V
Ğ				6.0	_	_	1.80	_	1.80	
				2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		6.0	5.9	6.0	_	5.9		V
			$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
				2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage	$V_{OL}$	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>		6.0		0.0	0.1	_	0.1	V
			$I_{OL} = 6 \text{ mA}$	4.5	_	0.17	0.26	_	0.33	
			I <sub>OL</sub> = 7.8 mA	6.0		0.18	0.26	_	0.33	
3-state output off-state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		6.0	_	_	±0.5	_	±5.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0			±0.1	_	±1.0	μА
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		6.0	_	_	4.0	_	40.0	μА

# Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Symbol Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V <sub>CC</sub> (V)	Тур.	Limit	Limit	
Minimum pulse width			2.0	_	75	95	
·	t <sub>W (H)</sub>	_	4.5	_	15	19	ns
(LE)			6.0	_	13	16	
Minimum set-up time			2.0	_	50	65	
·	ts	_	4.5	_	10	13	ns
(data)			6.0	_	9	11	
Minimum hold time			2.0	_	5	5	
	t <sub>h</sub>	_	4.5	_	5	5	ns
(data)			6.0	_	5	5	



AC Characteristics (input:  $t_r = t_f = 6$  ns)

Characteristics Symbol		Test Co	ndition	_		Ta = 25°0			a = o 85°C	Unit	
	,		CL (pF)	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max		
	tтьн			2.0	_	20	60	_	75		
Output transition time		_	50	4.5	_	6	12	_	15	ns	
	t <sub>THL</sub>			6.0		5	10	_	13		
				2.0		50	115	_	145		
			50	4.5	_	15	23	_	29		
Propagation delay time	$t_{pLH}$			6.0	_	13	20	_	25	ns	
(LE-Q)	$t_{pHL}$	_		2.0	_	60	155	_	195	115	
,			150	4.5	_	20	31	_	39		
				6.0	_	17	26	_	33		
				2.0	_	42	110	_	140		
			50	4.5	_	14	22	_	28		
Propagation delay time	$t_{pLH}$			6.0	_	12	19	_	24	ns	
(D-Q)	$t_{pHL}$	_		2.0	_	57	150	_	190	115	
,			150	4.5	_	19	30	_	38		
				6.0	_	16	26	_	32		
				2.0	_	55	140	_	175		
			50	4.5	_	17	28	_	35		
Output enable time	$t_{pZL}$	$R_L = 1 k\Omega$		6.0	_	14	24	_	30	ns	
Output enable time	$t_{pZH}$	KL = 1 K22		2.0	_	66	180	_	225	115	
			150	4.5	_	22	36	_	45		
				6.0	_	19	31	_	38		
				2.0	_	40	125	_	155		
Output disable time	t <sub>pLZ</sub>	$R_L = 1 k\Omega$	50	4.5	_	17	25	_	31	ns	
	t <sub>pHZ</sub>			6.0	_	15	21	_	26		
Input capacitance	C <sub>IN</sub>	_	_		_	5	10	_	10	pF	
Output capacitance	C <sub>OUT</sub>	_			_	10	_	_	_	pF	
Power dissipation capacitance	C <sub>PD</sub> (Note)	_	_		_	51	_	_	_	pF	

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

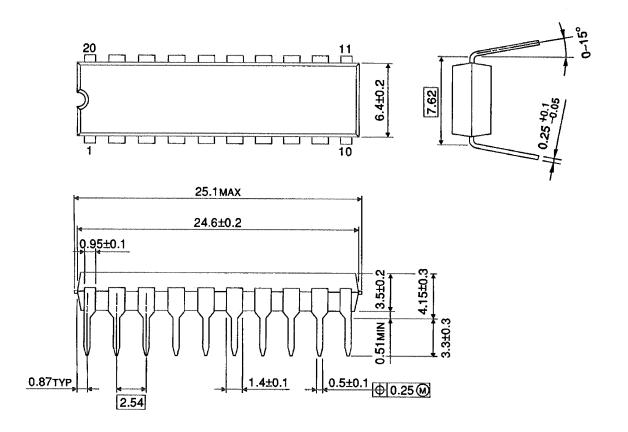
$$I_{CC}$$
 (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$  (per latch)

And the total CPD when n pcs. of latch operate can be gained by the following equation:

$$C_{PD}$$
 (total) = 33 + 18 · n

## **Package Dimensions**

DIP20-P-300-2.54A Unit: mm

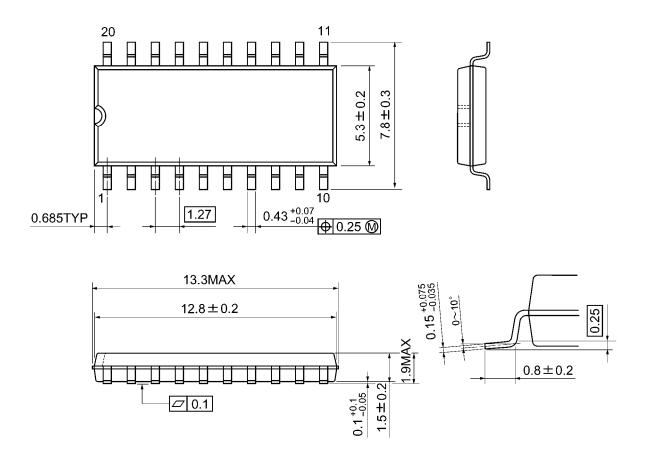


Weight: 1.30 g (typ.)



## **Package Dimensions**

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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